

NANO MATERIALS

Introduction - Concept of nanomaterials - quantum confinement and surface volume ratio.

Properties of nanomaterials: Catalytic, electrical, mechanical and optical properties.

Types of Nanomaterials: Zero dimensional (0-D), One dimensional (1-D), Two dimensional (2-D), Three Dimensional (3-D).

Synthesis of nanomaterials: Top down and bottom-up approaches- mechanical grinding by ball milling and sol -gel method.

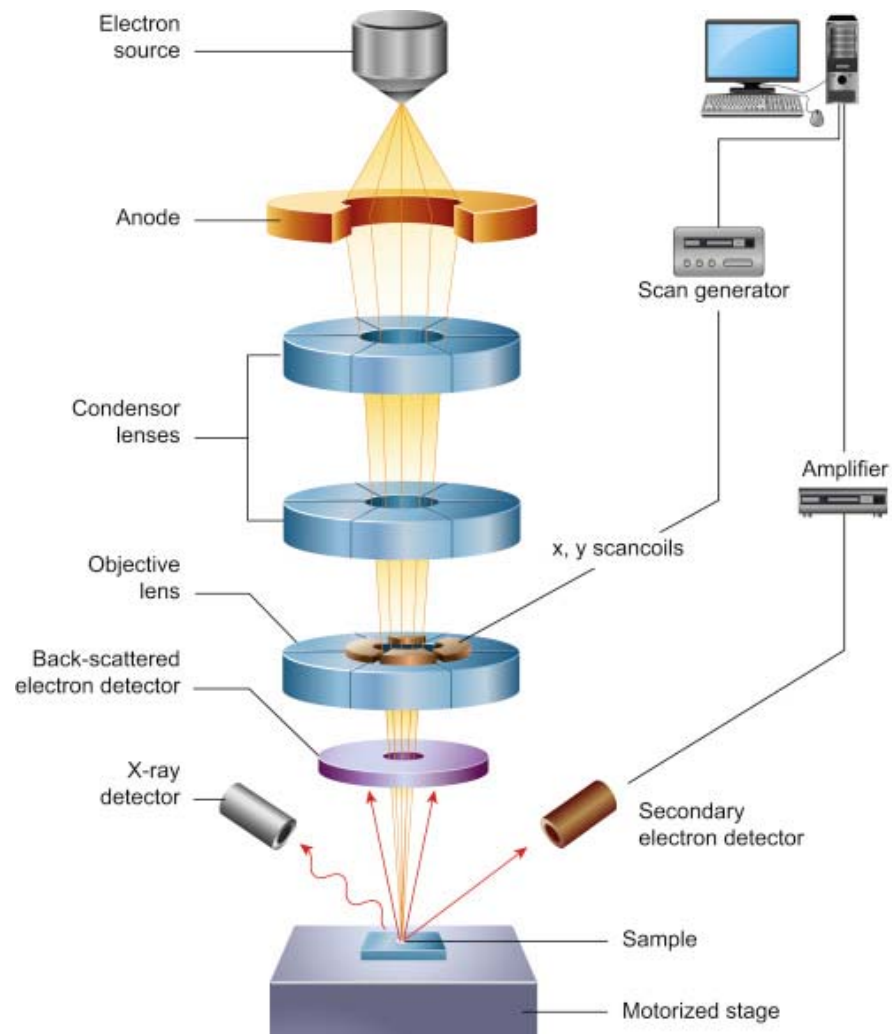
Graphene: Introduction, synthesis of graphene by chemical vapor deposition (CVD).

Carbon Nanotubes: Classification - single walled carbon nanotubes (SWCNTs- armchair, zig-zag, chiral) and Multi walled carbon nanotubes (MWCNTs- Russian doll and parchment model).

Synthesis of CNTs- Arc discharge and laser ablation methods- applications of CNTs.

Characterization of nanomaterials- Principle and block diagram of Scanning Electron Microscope (SEM), Atomic Force Microscope (AFM).

SCANNING ELECTRON MICROSCOPE (SEM)



Spatial resolution of imaging techniques

Resolution is diffraction limited

Abbe (1873) reported that smallest resolvable distance between two points (d) using conventional microscope may never be smaller than half the wavelength of the imaging light.

Limit of resolution of a microscope is given by,

$$\begin{aligned}\text{Limit of resolution} &= d = 0.61\lambda / \text{NA} \\ &= 0.61\lambda / \mu \sin\alpha\end{aligned}$$

where NA=Numerical Aperture of the microscope,

μ = Refractive index of the medium,

α = Half angle with the optical axis,

λ = Wavelength of light used.



<https://www.youtube.com/watch?v=6jkK5fhZesA>

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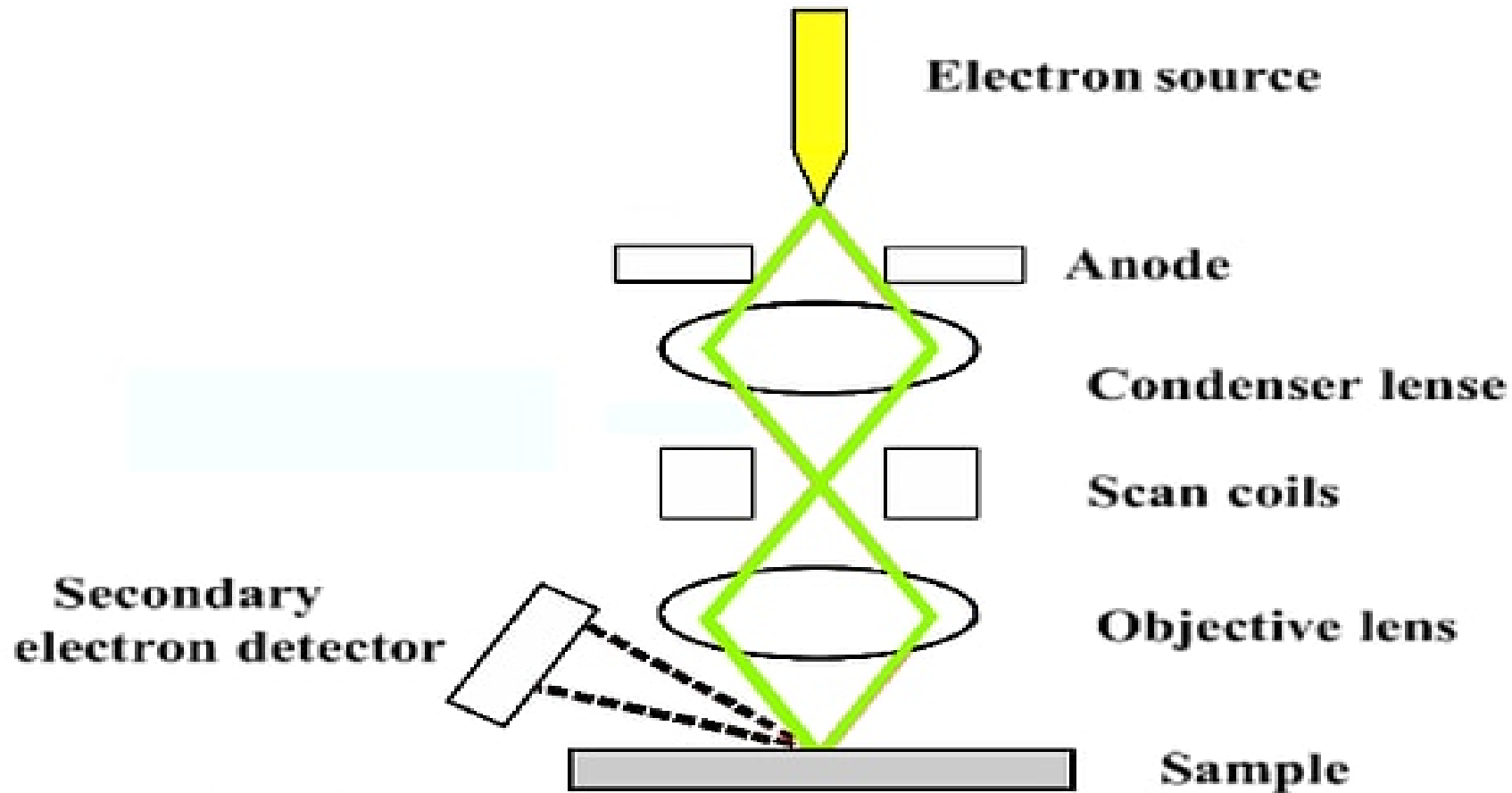
Scanning electron microscopes (SEMs) have become powerful and versatile tools for material characterization, especially nanomaterials in recent years, as the size of materials used in various applications decreasing.

Electron microscopes use electrons for imaging in a similar way that light microscopes use visible light. Unlike transmission electron microscopes (TEMs), which detect electrons that pass through a very thin specimen, SEMs use the electrons that are reflected or knocked off the near-surface region of a sample to create an image. Since the wavelength of electrons is much smaller than that of light, the resolution of SEMs is superior to that of a light microscope.

HOW IT WORKS:

In scanning electron microscopy, the electron beam scans the sample in a raster pattern. First, electrons are generated at the top of the column by the **electron source**. These are emitted when their thermal energy overcomes the work function of the source material. They are then accelerated and attracted by the positively-charged **anode**.

Scanning Electron Microscope



Block diagram

The entire electron column needs to be under vacuum. Like all components of an electron microscope, the electron source is sealed inside a special chamber to preserve vacuum and protect it against contamination, vibrations, and noise. Besides protecting the electron source from being contaminated, vacuum also allows the user to acquire a high-resolution image. In the absence of vacuum, other atoms and molecules can be present in the column. Their interaction with electrons causes the electron beam to deflect and reduces the image quality. High vacuum also increases the collection efficiency of electrons by the detectors that are in the column.

In a similar way to optical microscopes, lenses are used to control the path of the electrons. Because electrons cannot pass through glass, the lenses that are used are electromagnetic. They simply consist of coils of wires inside metal pole pieces. When current passes through the coils, a magnetic field is generated. As electrons are very sensitive to magnetic fields, their path inside the microscope column can be controlled by these electromagnetic lenses simply by adjusting the current that is applied to them.

Generally, two types of electromagnetic lenses are used: The **condenser** lens is the first lens that electrons meet as they travel towards the sample. This lens converges the beam before the electron beam cone opens again and is converged once more by the **objective** lens before hitting the sample. The condenser lens defines the size of the electron beam (which defines the resolution), while the main role of the objective lens is to focus the beam onto the sample.

The SEM's lens system also contains **scanning coils**, which are used to raster the beam onto the sample. In many cases, **apertures** are combined with the lenses to control the size of the beam.

Backscattered and secondary electrons

The interaction of electrons within a sample can generate many different types of electrons, photons, or irradiations. In the case of an SEM, the two types of electrons used for imaging are backscattered (BSE) and secondary electrons (SE).

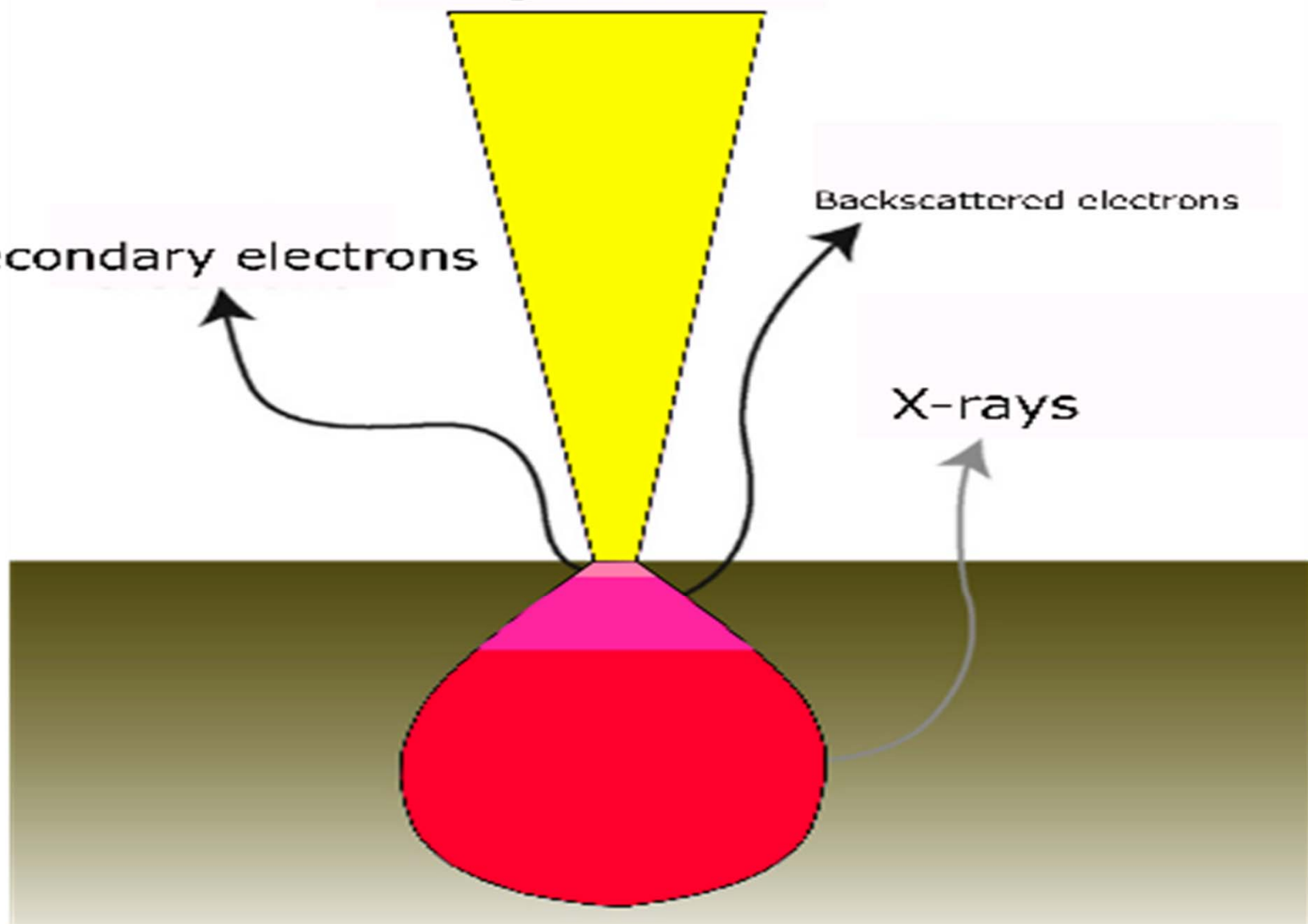
BSEs belong to the primary electron beam and are reflected back after elastic interactions between the beam and the sample. By contrast, secondary electrons originate from the atoms of the sample; they are a result of inelastic interactions between the electron beam and the sample.

Incoming electron beam

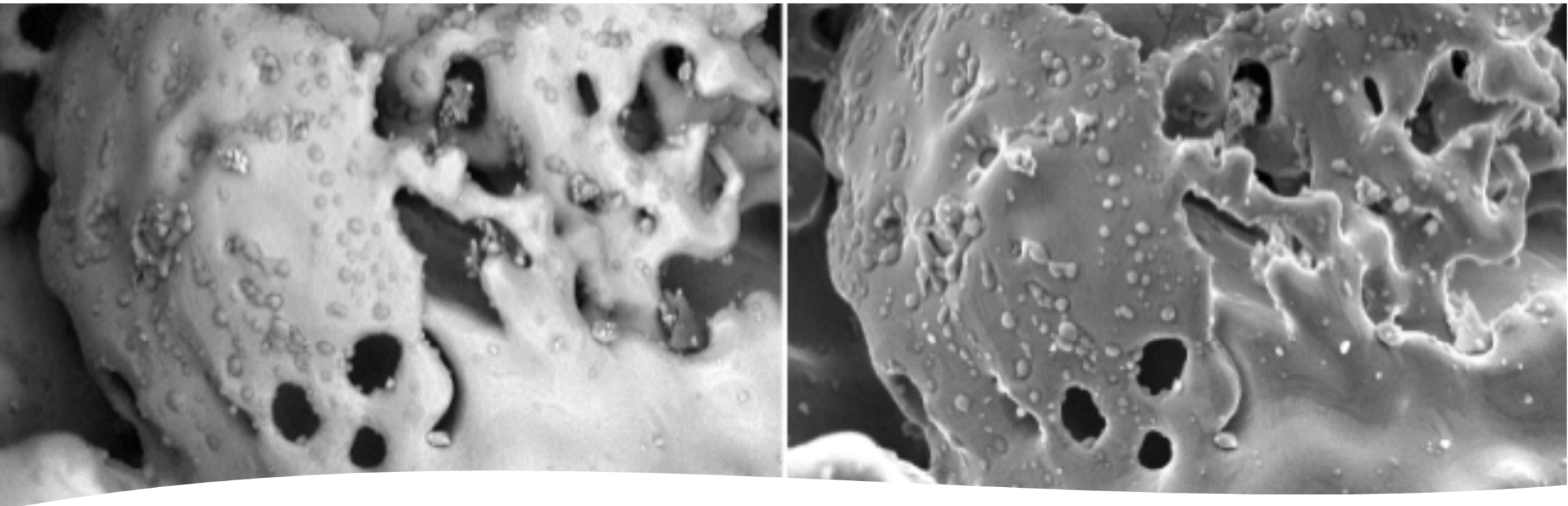
Secondary electrons

Backscattered electrons

X-rays



BSE (left) and SE (right) images of FeO₂ particles.



- Because BSEs come from deeper regions of the sample whereas SEs originate from surface regions, the two carry different types of information. BSE images show high sensitivity to differences in atomic number; the higher the atomic number, the brighter the material appears in the image. SE imaging can provide more detailed surface information

In many microscopes, detection of X-rays generated from the electron-matter interaction is also widely used to perform elemental analysis of the sample. Every material produces X-rays that have a specific energy; X-rays are the material's fingerprint. By detecting the energies of X-rays that come out of a sample with an unknown composition, it's possible to identify all the different elements that the sample contains.

How BSE & SE electrons are detected

BSEs and SEs are detected by different types of detectors. For the detection of BSEs, solid state detectors are placed above the sample, concentrically to the electron beam, to maximize BSE collection.

For the detection of SEs, the **Everhart-Thornley detector** is mainly used. It consists of a scintillator inside a Faraday cage, which is positively charged and attracts the SEs. The scintillator is then used to accelerate the electrons and convert them into light before reaching a photomultiplier for amplification. The SE detector is placed at an angle at the side of the electron to increase the efficiency of detecting SEs, which are then used to form a 3D-image of the sample shown on a PC monitor.

As you can see, there are different processes that the electrons must go through before an image can be shown on your monitor. Of course, you don't have to wait for the electrons to finish their journey; the whole process is almost instantaneous, in the range of nanoseconds. At the same time, every “step” of an electron inside the column needs to be pre-calculated and controlled with precision in order to obtain a high-quality image.

Backscattered electron image of Tungsten particles

